

JAN2N3439 Information



For Reference Only

Part Number JAN2N3439

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN 350V 1A

Package TO-205AD, TO-39-3 Metal Can

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









JAN2N3439 Specifications

Manufacturer Part Number	JAN2N3439
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-205AD, TO-39-3 Metal Can
Series	Military, MIL-PRF-19500/368
Transistor Type	NPN
Current - Collector (Ic) (Max)	1A
Voltage - Collector Emitter Breakdown (Max)	350V
Vce Saturation (Max) @ Ib, Ic	500mV @ 4mA, 50mA
Current - Collector Cutoff (Max)	2μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	40 @ 20mA, 10V
Power - Max	800mW
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-205AD, TO-39-3 Metal Can
Supplier Device Package	TO-39 (TO-205AD)
	Report errors?

JAN2N3439 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

JAN2N3439 Payment Methods

































If you have any question about JAN2N3439, please do not hesitate to contact us!

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